onsemi

Silicon Carbide (SiC) Diodes - EliteSiC, TO247-3, 50 A, 1200 V SiC Merged PiN-Schottky (MPS) Diode

UJ3D1250K

Description

onsemi offers the 3rd generation of high performance SiC Merged-PiN-Schottky (MPS) diodes. With zero reverse recovery charge and 175 °C maximum junction temperature, these diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.

Features

- Maximum Operating Temperature of 175 °C
- Easy Paralleling
- Extremely Fast Switching Not Dependent on Temperature
- No Reverse or Forward Recovery
- Enhanced Surge Current Capability, MPS Structure
- 100% UIS Tested
- This Device is Halogen Free and RoHS Compliant with Exemption 7a, Pb-Free 2LI (on second level interconnection)

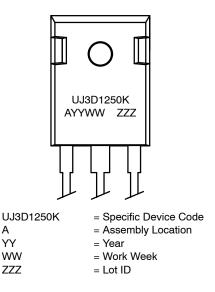
Typical Applications

- Power Converters
- Industrial Motor Drives
- Switch Mode Power Supplies
- Power Factor Correction Modules

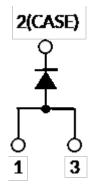


TO247-3 15.90x20.96x5.03, 5.44P CASE 340AK

MARKING DIAGRAM



PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

UJ3D1250K

MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Value	Unit
DC Blocking Voltage	V _R		1200	V
Repetitive Peak Reverse Voltage, $T_J = 25 \ ^{\circ}C$	V _{RRM}		1200	V
Surge Peak Reverse Voltage	V _{RSM}		1200	V
Maximum DC Forward Current	١ _F	T _C = 112 °C	50	А
Non-Repetitive Forward Surge Current Sine Half-wave	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms	275	A
Repetitive Forward Surge Current Sine	I _{FRM}	T _C = 25 °C, t _p = 10 ms	163.5	А
Half-Wave, D=0.1		T _C = 110 °C, t _p = 10 ms	99.6	
Non-Repetitive Peak Forward Current	I _{F,max}	T _C = 25 °C, t _p = 10 μs	2400	А
		T _C = 110 °C, t _p = 10 μs	2400	
i ² t Value	∫i ² dt	T _C = 25 °C, t _p = 10 ms	378	A ² s
Power Dissipation	P _{tot}	T _C = 25 °C	319	W
		T _C = 112 °C	134	
Maximum Junction Temperature	T _{J,max}		175	°C
Operating and Storage Temperature	T _J , T _{STG}		–55 to 175	°C
Soldering Temperatures, Wave Soldering Only Allowed at Leads	T _{sold}	1.6 mm From Case for 10s	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Thermal Resistance, Junction-to-Case	R_{\thetaJC}		-	0.36	0.47	°C/W

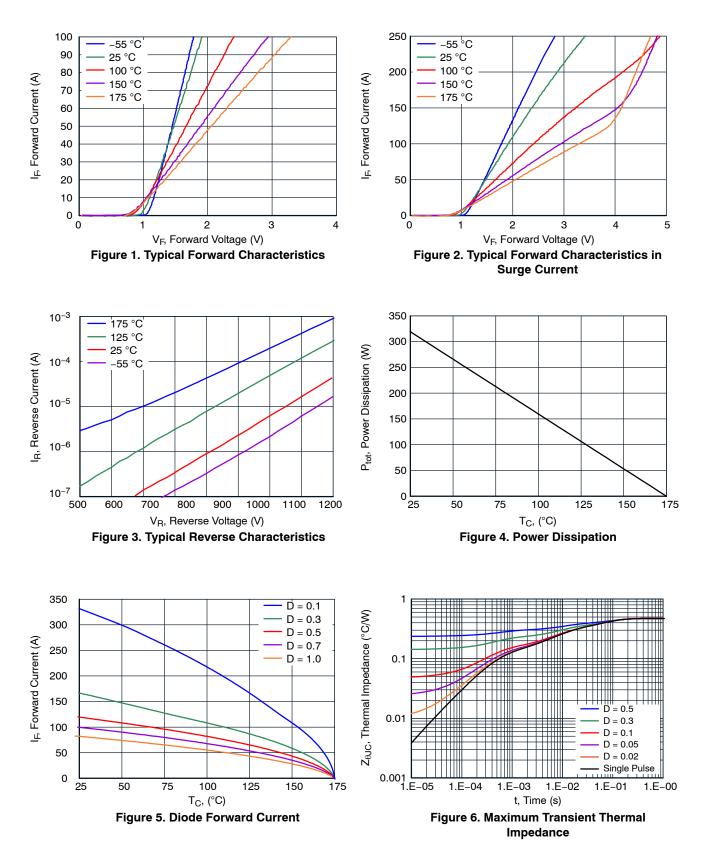
ELECTRICAL CHARACTERISTICS (T_J = +25 °C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Forward Voltage	V _F	I _F = 50 A, T _J = 25 °C	-	1.5	1.7	V
		I _F = 50 A, T _J = 150 °C	-	1.95	2.4	
		I _F = 50 A, T _J = 175 °C	-	2.2	2.7	
Reverse Current	I _R	V _R = 1200 V, T _J = 25 °C	-	52	400	μΑ
		V _R = 1200 V, T _J = 175°C	-	900	-	
Total Gate Leakage Current (Note 1)	Q _C	V _R = 800 V	-	240	-	nC
Total Capacitance	С	V _R = 1 V, f = 1 MHz	-	2340	-	pF
		V _R = 400 V, f = 1 MHz	-	224	-	1
		V _R = 800 V, f = 1 MHz	-	198	-	1
Capacitance Stored Energy	E _C	V _R = 800 V	-	72	-	μJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Q_C is independent on T_J , di_F/dt, and I_F as shown in the application note AND90316/D.

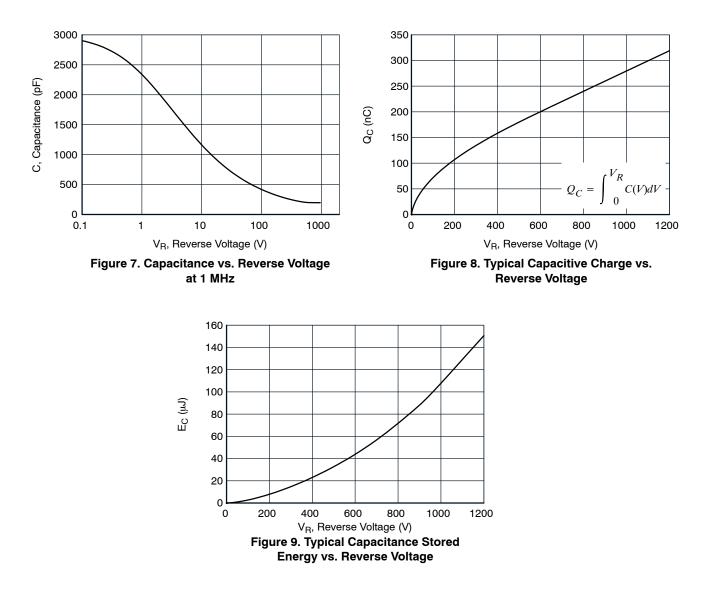
UJ3D1250K

TYPICAL PERFORMANCE DIAGRAMS



UJ3D1250K

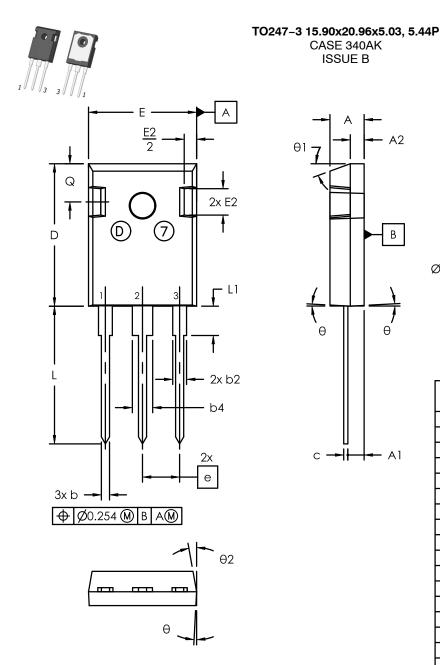
TYPICAL PERFORMANCE DIAGRAMS (continued)



ORDERING INFORMATION

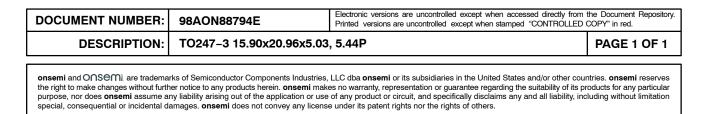
Part Number	Marking	Package	Shipping
UJ3D1250K	UJ3D1250K	TO247-3 15.90x20.96x5.03, 5.44P (Pb-Free, Halogen Free)	600 / Tube

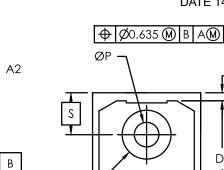
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NOTE:

- 1. Dimensioning and tolerancing as per ASME Y14.5 2018
- 2. Controlling dimension : millimeters
- 3. Package Outline in compliance with JEDEC standard var. AD.
- 4. Dimensions D & E does not include mold flash.
- ØP to have max draft angle of 1.7° to the top with max. hole 5. diameter of 3.91mm.





3

2

1

ØP1

θ

- A1

DATE 14 APR 2025

D2

Dl

 ◄-	—— E1 —					
SYM	millimeters					
31/01	MIN	NOM	MAX			
A	4.70	5.03	5.31			
A1	2.21	2.40	2.59			
A2	1.50	2.03	2.49			
b	0.99	1.20	1.40			
b2	1.65	2.03	2.39			
b4	2.59	3.00	3.43			
С	0.38	0.60	0.89			
C D	20.70	20.96	21.46			
D1	13.08	_	-			
D2	0.51	1.19	1.35			
E	15.49	15.90	16.26			
е		5.44 BSC				
E1	13.00	13.30	13.60			
E2	3.43	3.89	5.20			
L	19.62	20.27	20.32			
L1	-	-	4.50			
ØP	3.40	3.60	3.80			
ØP1	7.06	7.19	7.39			
Q S	5.38	5.62	6.20			
S	6.15 BSC					
θ	3°					
θ1	20°					
θ2	10°					

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ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>